



STB7102

0.5/2.5 GHz UHF LO BUFFER AMPLIFIER

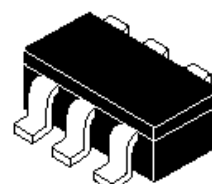
- OPERATING FREQUENCY 500-2500MHz
- LOW CURRENT CONSUMPTION
- EXCELLENT ISOLATION
- ULTRA MINIATURE SOT323-6L PACKAGE

APPLICATIONS

- BUFFER AMPLIFIER FOR 0.5/2.5 GHz APPLICATIONS
- CDMA/PCS LO BUFFER AMPLIFIER

DESCRIPTION

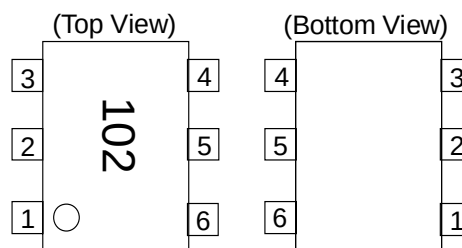
The STB7102, designed for RF Mobile Phone applications (0.5/2.5GHz), is an high isolation Local Oscillator Buffer Amplifier. Manufactured in the third generation of ST proprietary bipolar process, it offers an excellent isolation and a good linearity using only 4mA current consumption. The STB7102 is housed in an ultra miniature package SOT323-6L surface mount package.



SOT323-6L (SC70)

ORDER CODE
STB7102TR

BRANDING
102



PIN CONNECTION

Pin No.	Pin Name
1	INPUT
2	GND
3	GND
4	OUTPUT
5	GND
6	VCC

ABSOLUTE MAXIMUM RATINGS

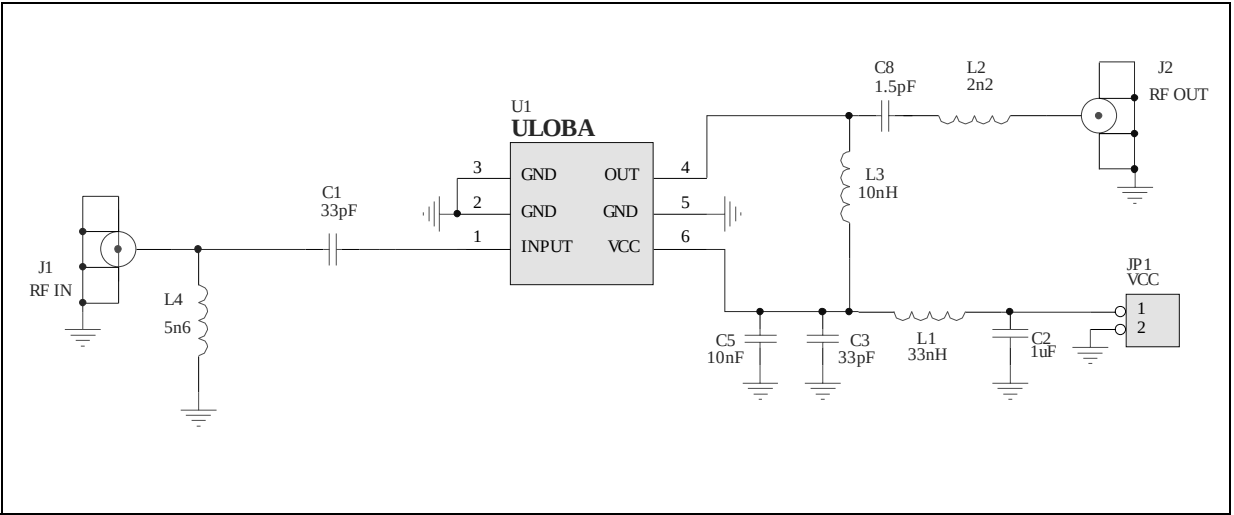
Symbol	Parameter	Conditions	Value	Unit
V _{cc}	Supply voltage		3.3	V
T _{stg}	Storage temperature		-40 to +100	°C
T _a	Operating ambient temperature		-30 to +85	°C

ELECTRICAL CHARACTERISTICS (*CELL BAND*)

($T_a = +25^{\circ}\text{C}$, $V_{cc} = 2.7\text{V}$, $Z_s = Z_L = 50\Omega$, tested in circuit shown in fig.1, unless otherwise specified)

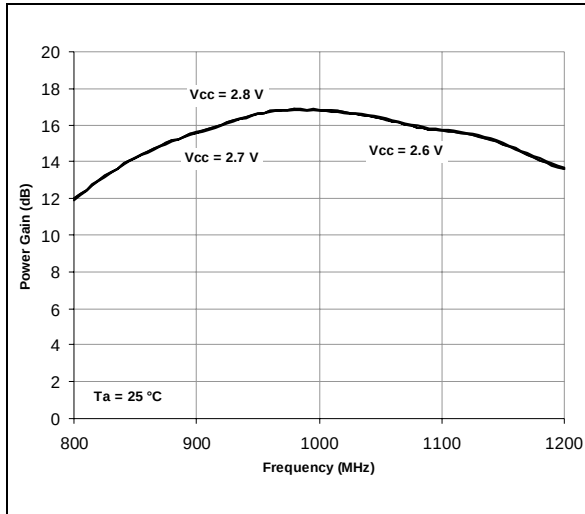
Symbol	Parameters	Test Conditions	Min	Typ	Max	Unit
Freq.	Frequency Range		990		1030	MHz
Vcc	Supply Voltage		2.6	2.7	2.8	V
Icc	Current Consumption		3.3	4.3	5.3	mA
P1dB	Output Power at 1dB Compression Point	F = 1010 MHz		-2		dBm
Gp	Power Gain	F = 1010 MHz		16.7		dB
NF	Noise Figure	F = 1010 MHz		2.7		dB
Isol.	Reverse Isolation	F = 1010 MHz		45		dB
RLin	Input Return Loss	F = 1010 MHz		30		dB
RLout	Output Return Loss	F = 1010 MHz		17.8		dB

Figure 1 Cell Band Application Circuit Configuration

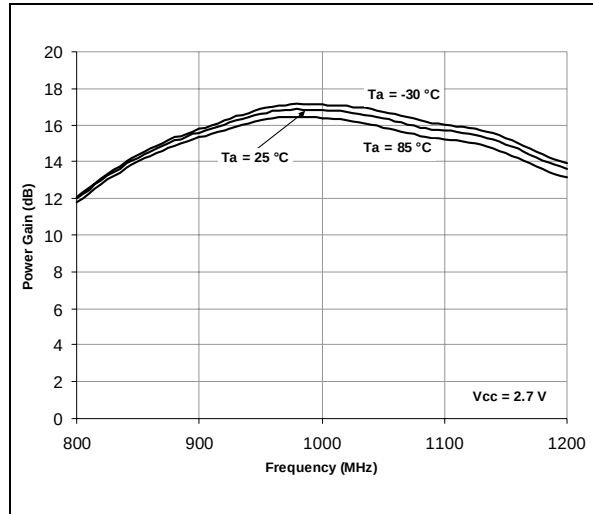


TYPICAL PERFORMANCE (CELL BAND)

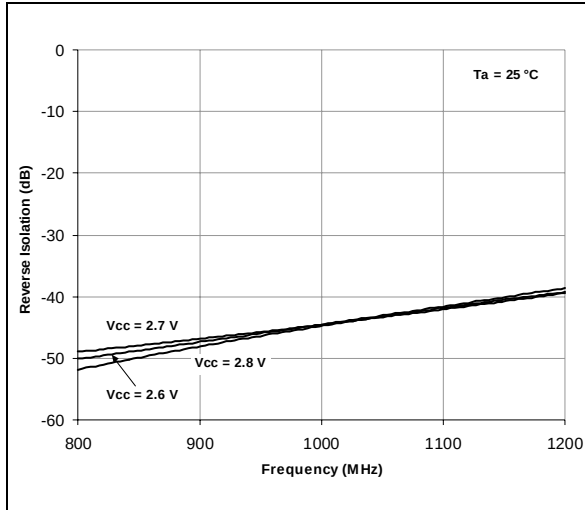
Power Gain vs. Frequency and Voltage



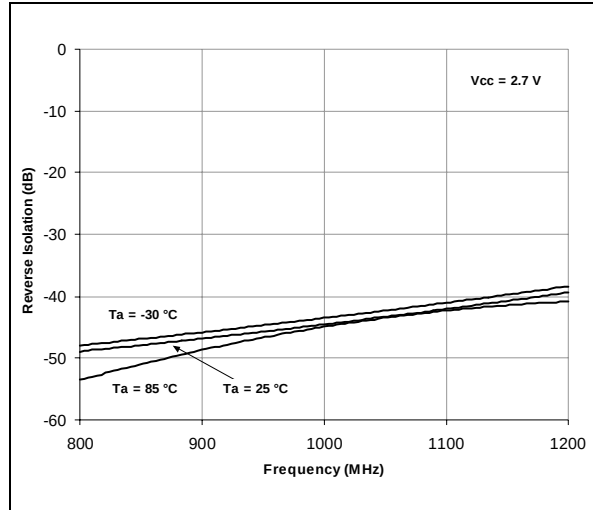
Power Gain vs. Frequency and Temperature



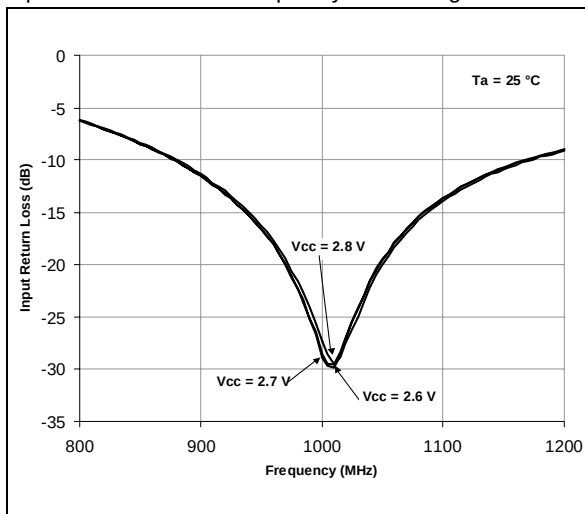
Reverse Isolation vs. Frequency and Voltage



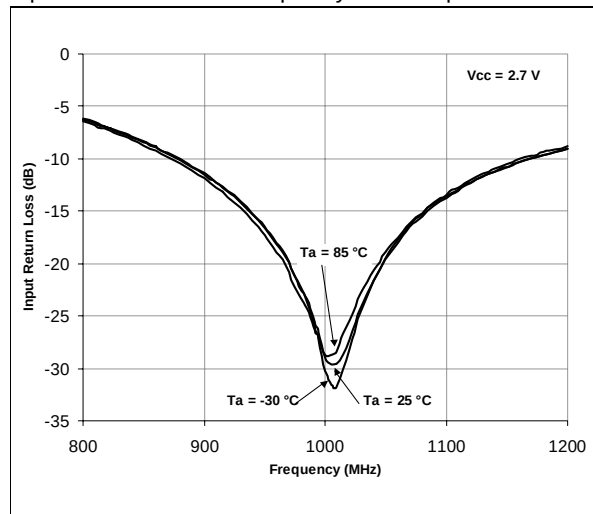
Reverse Isolation vs. Frequency and Temperature



Input Return Loss vs. Frequency and Voltage

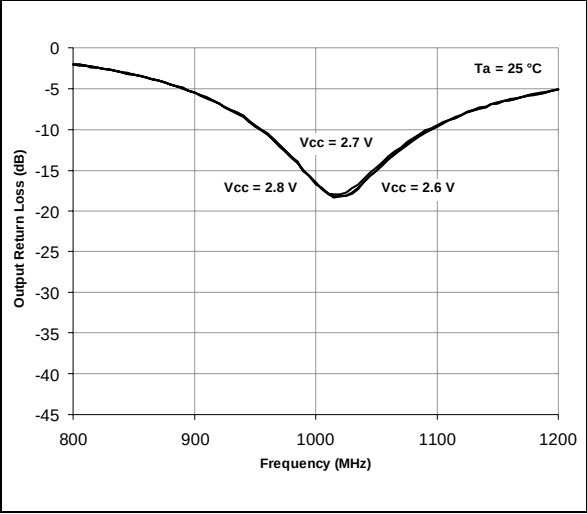


Input Return Loss vs. Frequency and Temperature

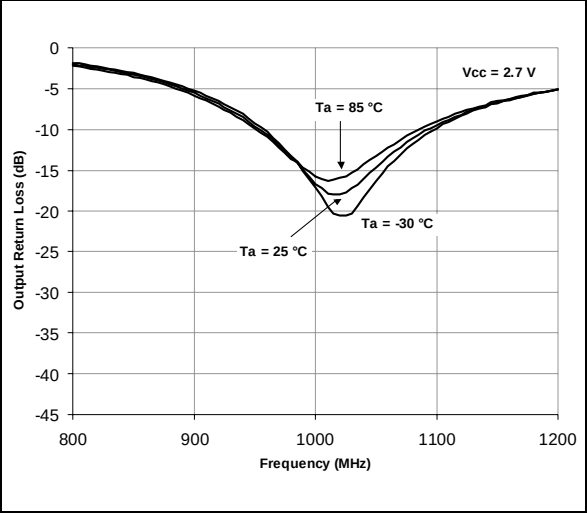


TYPICAL PERFORMANCE (CELL BAND)

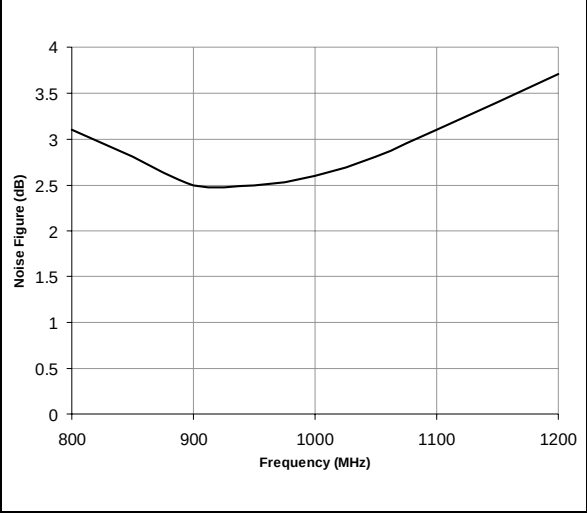
Output Return Loss vs. Frequency and Voltage



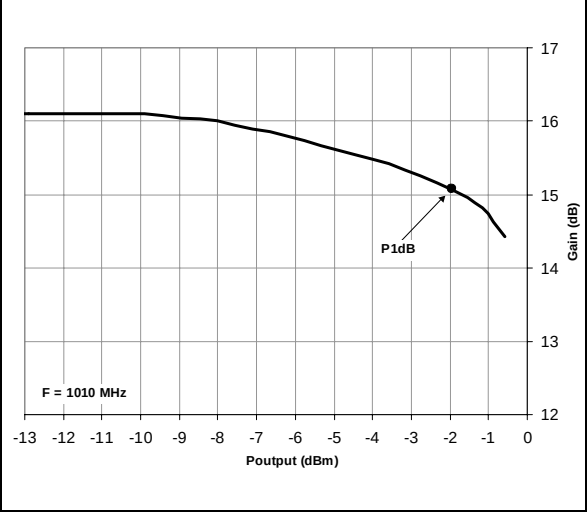
Output Return Loss vs. Frequency and Temperature



Noise Figure vs. Frequency



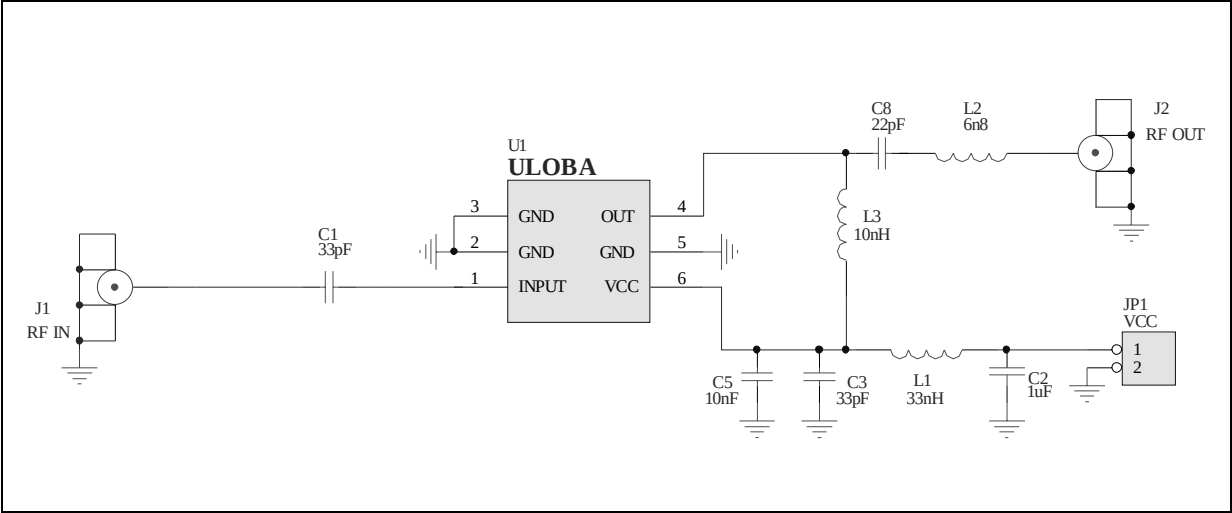
Output Power @ 1dB compression point



ELECTRICAL CHARACTERISTICS (PCS BAND)
(T_a = +25°C, V_{cc} = 2.7V, Z_s = Z_L = 50Ω, tested in circuit shown in fig.2, unless otherwise specified)

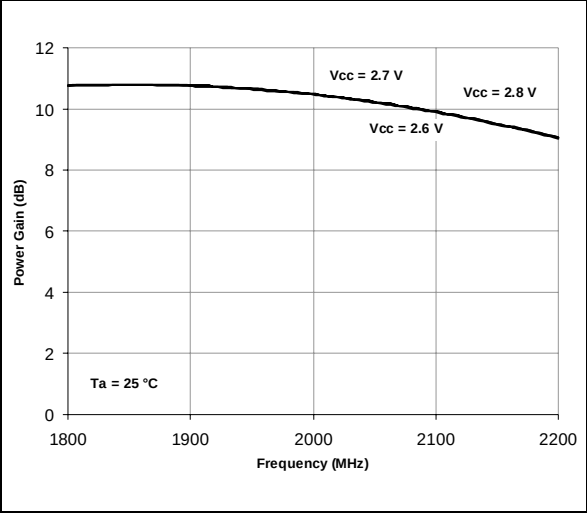
Symbol	Parameters	Test Conditions	Min	Typ	Max	Unit
Freq.	Frequency Range		2040		2135	MHz
Vcc	Supply Voltage		2.6	2.7	2.8	V
Icc	Current Consumption		3.3	4.3	5.3	mA
P1dB	Output Power at 1dB Compression Point	F = 2085 MHz		-1		dBm
Gp	Power Gain	F = 2085 MHz		10		dB
NF	Noise Figure	F = 2085 MHz		5		dB
Isol.	Reverse Isolation	F = 2085 MHz		41		dB
RLin	Input Return Loss	F = 2085 MHz		17		dB
RLout	Output Return Loss	F = 2085 MHz		24		dB

Figure 2 PCS Band Application Circuit Configuration

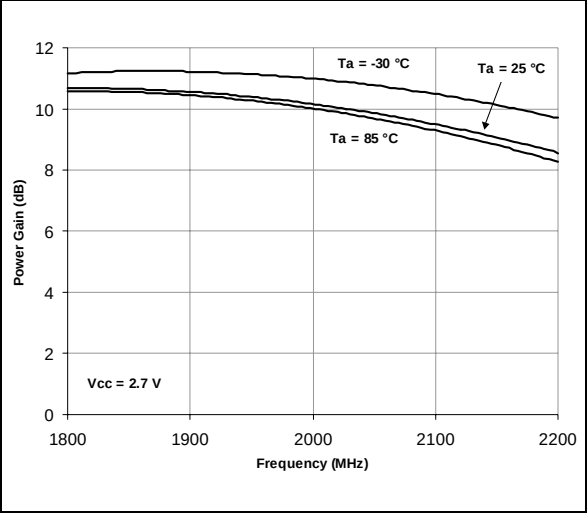


TYPICAL PERFORMANCE (PCS BAND)

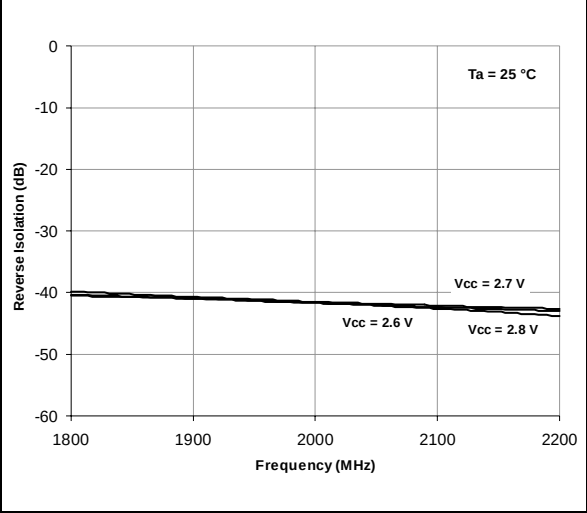
Power Gain vs. Frequency and Voltage



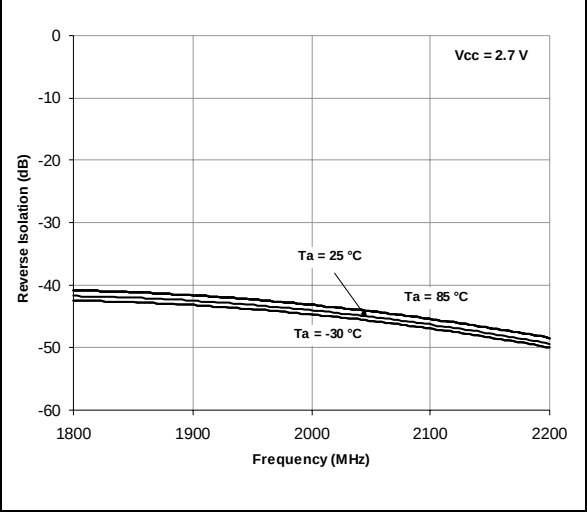
Power Gain vs. Frequency and Temperature



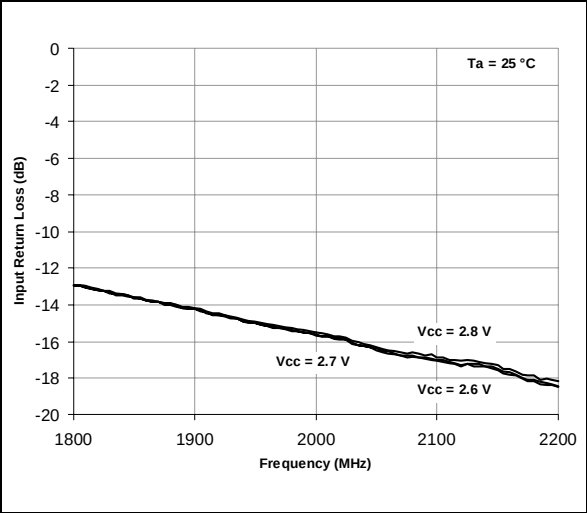
Reverse Isolation vs. Frequency and Voltage



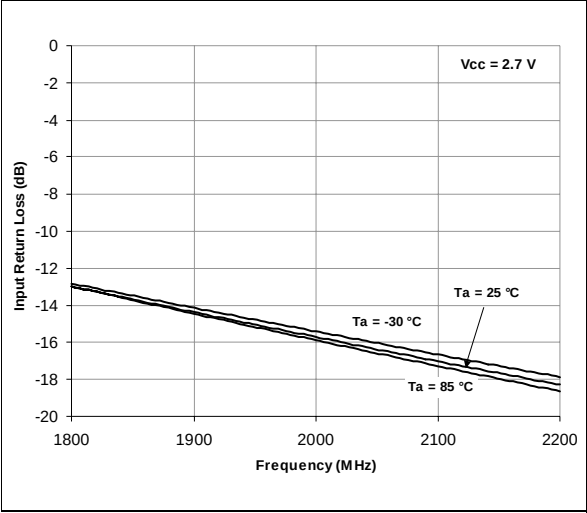
Reverse Isolation vs. Frequency and Temperature



Input Return Loss vs. Frequency and Voltage

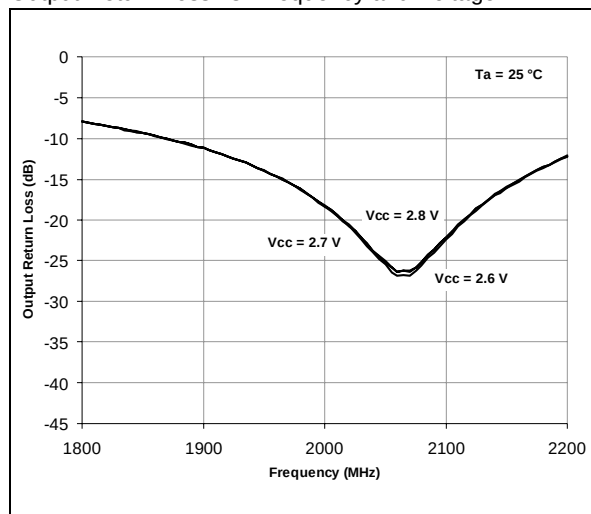


Input Return Loss vs. Frequency and Temperature

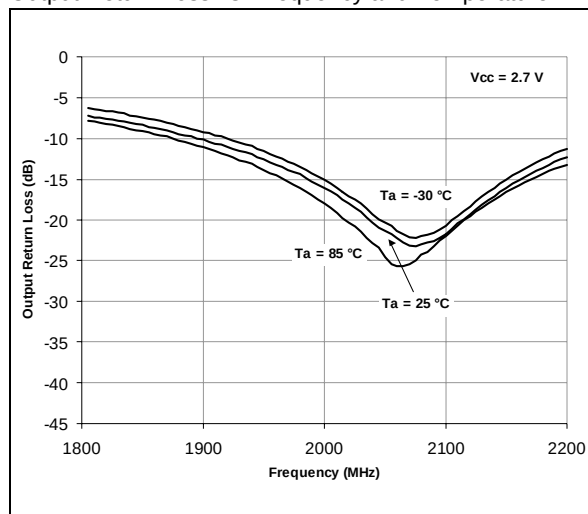


TYPICAL PERFORMANCE (PCS BAND)

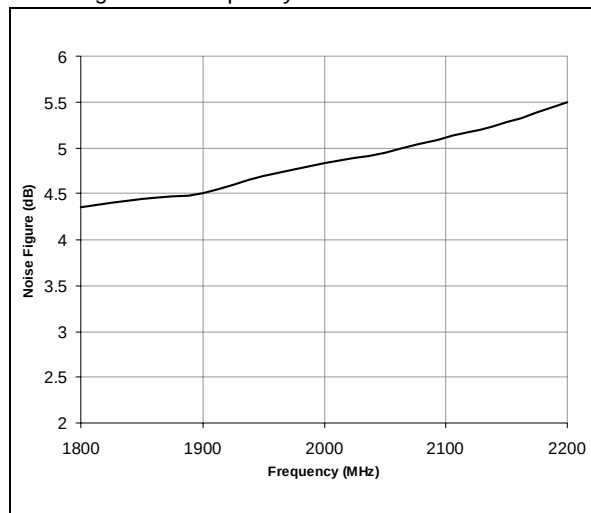
Output Return Loss vs. Frequency and Voltage



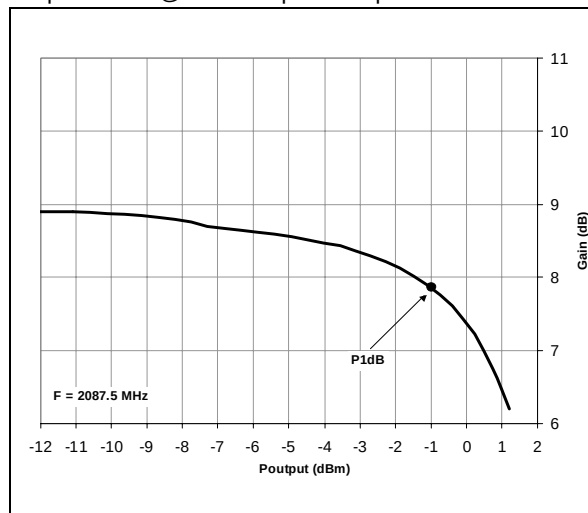
Output Return Loss vs. Frequency and Temperature



Noise Figure vs. Frequency

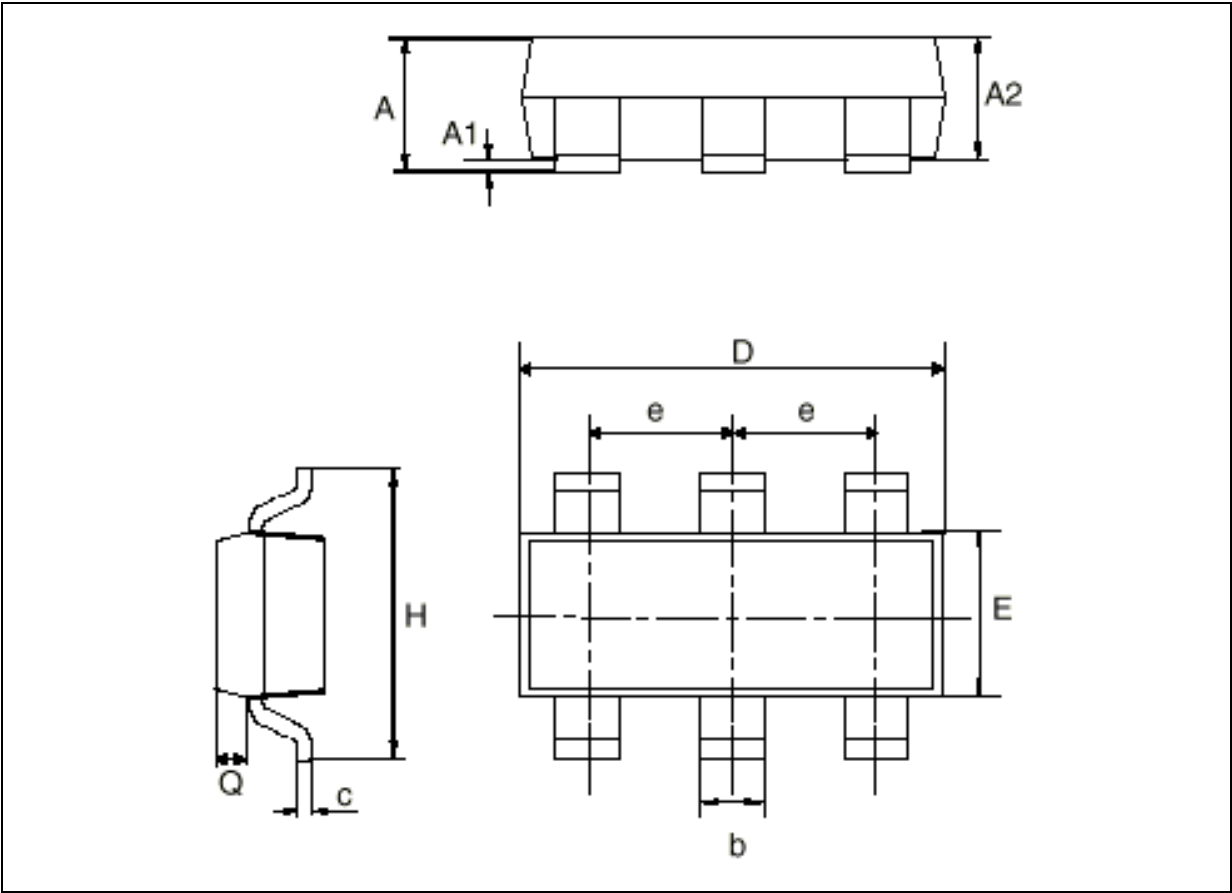


Output Power @ 1dB compression point



SOT323-6L MECHANICAL DATA

DIM.	mm			Inch		
	MIN.	TYP.	MAX	MIN.	TYP.	MAX
A	0.8		1.1	0.031		0.043
A1	0		0.1	0		0.004
A2	0.8		1	0.0031		0.039
b	0.15		0.3	0.006		0.012
c	0.1		0.18	0.004		0.007
D	1.8		2.2	0.071		0.088
E	1.15		1.35	0.045		0.59
e		0.65			0.025	
H	1.8		2.4	0.071		0.094
Q	0.1		0.4	0.004		0.016



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